NSN 5961-00-415-1956



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-00-415-1956 **Inclosure Material:** Metal **Overall Length:** Between 0.170 inches and 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.209 inches and 0.230 inches **Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-18 **Electrode Internally-electrically Connected To Case:** Gate **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 10.0 drain supply voltage and -10.0 gate to source cutoff voltage **Current Rating Per Characteristic:** 20.00 milliamperes drain current **Power Rating Per Characteristic:** 0.5 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No

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